

## »Features

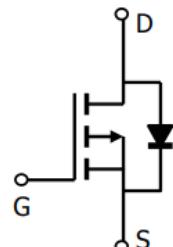
$V_{DS} = -20V$

$I_D = -2A$

$R_{DS(ON)} @ V_{GS} = -4.5V, \text{ Max } = 135m\Omega$

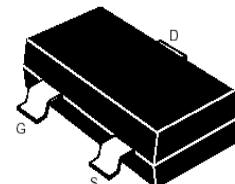
$R_{DS(ON)} @ V_{GS} = -2.5V, \text{ Max } = 190m\Omega$

## »Pin Configurations



## »General Description

- Advanced trench process technology
- High Density Cell Design For Ultra Low On-Resistance
- SOT-323 for Surface Mount Package.



## »Applicatin

- PWM applications
- Load Switch
- Power Management

## »Absolute Maximum Ratings @ $T_A=25^\circ C$ unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current	$I_D$	-2.0	A
Pulsed Drain Current (note1)	$I_{DM}$	-10	A
Power Dissipation	$P_D (Ta=25^\circ C)$	0.3	W
Thermal Resistance Junction to Ambient(note2)	$R_{\theta JA}$	417	$^\circ C/mW$
Junction Temperature	$T_j$	150	$^\circ C$
Storage Temperature	$T_{stg}$	-55 ~ 150	$^\circ C$

»**Electrical Characteristics** @ $T_A=25^\circ\text{C}$  unless otherwise noted

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{BR(DSS)}$	$V_{GS}=0V, I_D=-250\mu\text{A}$	-20			V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$I_D=-250\mu\text{A}, V_{GS}=V_{DS}$	-0.4		-1.1	V
Gate-body leakage current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$			$\pm 100$	nA
Zero gate voltage drain current	$I_{DSS}$	$V_{DS}=-20V, V_{GS}=0V$			-1	$\mu\text{A}$
Drain-source on-resistance(note1)	$R_{DS(ON)}$	$V_{GS}=-4.5V, I_D=-2.0\text{A}$			135	$\text{m}\Omega$
		$V_{GS}=-2.5V, I_D=-1.5\text{A}$			190	
Forward tranconductance(note1)	$g_{FS}$	$D_{GS}=-5V, I_D=-4\text{A}$	5			S
Drain-Source Diode Forward Voltage(note1)	$V_{SD}$	$V_{GS} = 0V, I_{SD} = -0.7\text{A}$			-1.2	V
<b>Dynamic Characteristics(note2)</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=-10V, V_{GS}=0V,$ $f=1\text{MHz}$		405		pF
Output Capacitance	$C_{oss}$			75		
Reverse Transfer Capacitance	$C_{rss}$			55		
<b>Switching Characteristics(note2)</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD}=-10V, I_{DS}=-1\text{A},$ $V_{GEN}=-4.5V, R_L=10\Omega,$			20	ns
Turn-on rise time	$t_r$				60	ns
Turn-off delay time	$t_{d(off)}$				50	ns
Turn-off fall time	$t_f$				20	ns

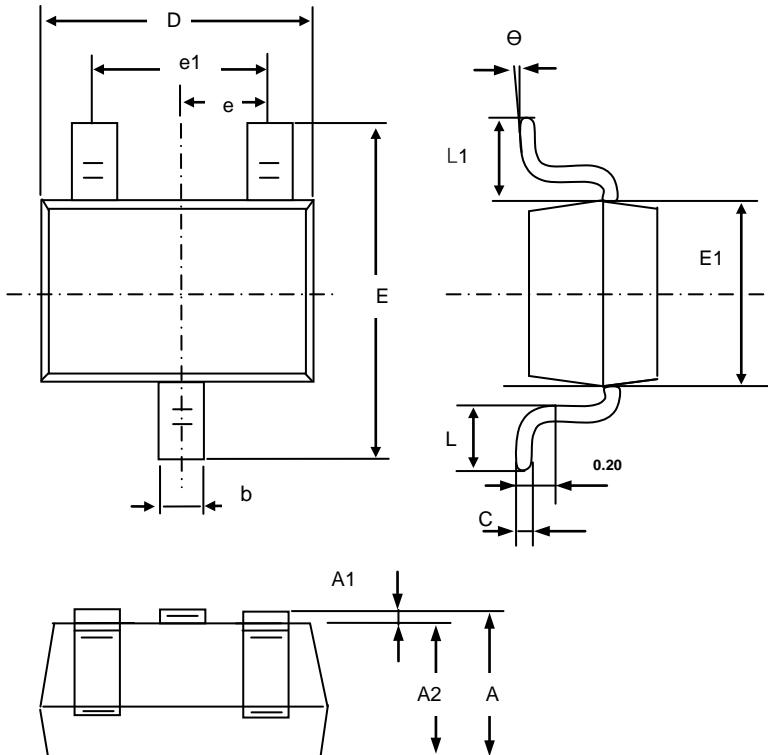
**Notes :**

Pulse test : Pulse width  $\leq 300 \mu\text{ s}$ , duty cycle  $\leq 2\%$ .

These parameter have no way to verify.

## »Package Information

SOT-323



Symbol	Dim in mm		
	Min	Nor	Max
A	0.90	1.00	1.10
A1	0.00	0.05	0.10
A2	0.90	0.95	1.00
b	0.20	0.30	0.40
c	0.08	0.12	0.15
D	2.00	2.10	2.20
E	2.15	2.30	2.45
E1	1.15	1.25	1.35
e	0.650TPY.		
e1	1.2	1.3	1.4
L	0.26	0.36	0.46
L1	0.525REF.		
θ	0°	4°	8°

## »Ordering information

Order code	Package	Marking	Base qty	Delivery mode
BMSN3139	SOT-323	39K	3K	Tape and reel